## Product Summary

| $BV_{DSS}$ | $R_{DS(ON)}$ Max | $I_D$ Max $T_A$ = +25°C |
|---|---|---|
| 12V | 8mΩ @ $V_{GS}$ = 4.5V | 12.2A |
| | 11.6mΩ @ $V_{GS}$ = 2.5V | 9.8A |

## Description

This MOSFET is designed to minimize the on-state resistance ($R_{DS(ON)}$) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

## Applications

- Battery-management applications
- Power-management functions
- DC-DC converters

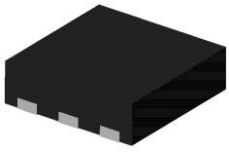
## Features

- 0.6mm Profile – Ideal for Low Profile Applications
- PCB Footprint of 4mm$^2$
- Low Gate Threshold Voltage
- Fast Switching Speed
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability. https://www.diodes.com/quality/product-definitions/**
- **An automotive-compliant part is available under a separate datasheet (DMN1008UFDFQ)**

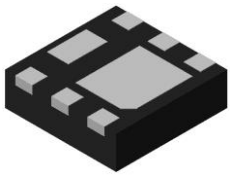
## Mechanical Data

- Package: U-DFN2020-6
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 e4
- Weight: 0.0065 grams (Approximate)

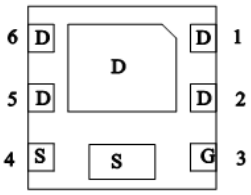
U-DFN2020-6 (Type F)



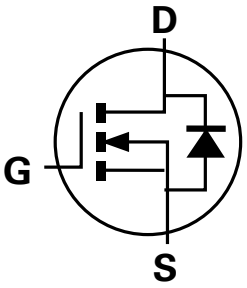
Top View



Bottom View




Pinout
Bottom View




Internal Schematic

## Ordering Information (Note 4)

| Orderable Part Number | Package | Reel Size (inches) | Packing | |
|---|---|---|---|---|
| | | | Qty. | Carrier |
| DMN1008UFDF-7 | U-DFN2020-6 (Type F) | 7 | 3,000 | Reel |
| DMN1008UFDF-13 | U-DFN2020-6 (Type F) | 13 | 10,000 | Reel |

Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.


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## Marking Information

Site 1




8N = Product Type Marking Code
YM = Date Code Marking
Y = Year (ex: N = 2026)
M = Month (ex: 9 = September)

Date Code Key

| Year | 2015 | - | 2026 | 2027 | 2028 | 2029 | 2030 | 2031 | 2032 | 2033 | 2034 | 2035 |
|---|---|---|---|---|---|---|---|---|---|---|---|---|
| Code | C | - | N | P | R | S | T | U | V | W | X | Y |

| Month | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
|---|---|---|---|---|---|---|---|---|---|---|---|---|
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | O | N | D |

Site 2




8N = Product Type Marking Code
YWX = Date Code Marking
Y = Year (ex: 6 = 2026)
W = Week (ex: a = Week 27; z Represents Week 52 and 53)
X = Internal Code (ex: U = Monday)

Date Code Key

| Year | 2015 | - | 2026 | 2027 | 2028 | 2029 | 2030 | 2031 | 2032 | 2033 | 2034 | 2035 |
|---|---|---|---|---|---|---|---|---|---|---|---|---|
| Code | 5 | - | 6 | 7 | 8 | 9 | 0 | 1 | 2 | 3 | 4 | 5 |

| Week | 1-26 | 27-52 | 53 |
|---|---|---|---|
| Code | A-Z | a-z | z |

| Internal Code | Sun | Mon | Tue | Wed | Thu | Fri | Sat |
|---|---|---|---|---|---|---|---|
| Code | T | U | V | W | X | Y | Z |


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## Maximum Ratings (@$T_A$ = +25°C, unless otherwise specified.)

| Characteristic | | | Symbol | Value | Unit |
|---|---|---|---|---|---|
| Drain-Source Voltage | | | $V_{DSS}$ | 12 | V |
| Gate-Source Voltage | | | $V_{GSS}$ | ±8 | V |
| Continuous Drain Current, $V_{GS}$ = 4.5V (Note 6) | Steady State | $T_A$ = +25°C<br>$T_A$ = +70°C | $I_D$ | 12.2<br>9.8 | A |
| Pulsed Drain Current (380µs Pulse, Duty Cycle = 1%) | | | $I_{DM}$ | 60 | A |
| Continuous Source-Drain Diode Current (Note 6) | | $T_A$ = +25°C | $I_S$ | 1.8 | A |
| Avalanche Current, L = 0.1mH (Note 7) | | | $I_{AS}$ | 16.4 | A |
| Avalanche Energy, L = 0.1mH (Note 7) | | | $E_{AS}$ | 13.5 | mJ |

## Thermal Characteristics

| Characteristic | | Symbol | Value | Unit |
|---|---|---|---|---|
| Total Power Dissipation (Note 5) | $T_A$ = +25°C | $P_D$ | 0.7 | W |
| | $T_A$ = +70°C | | 0.4 | |
| Thermal Resistance, Junction to Ambient (Note 5) | Steady State | $R_{\theta JA}$ | 168 | °C/W |
| Total Power Dissipation (Note 6) | $T_A$ = +25°C | $P_D$ | 1.7 | W |
| | $T_A$ = +70°C | | 1.0 | |
| Thermal Resistance, Junction to Ambient (Note 6) | Steady State | $R_{\theta JA}$ | 74 | °C/W |
| Thermal Resistance, Junction to Case (Note 6) | | $R_{\theta JC}$ | 12 | °C/W |
| Operating and Storage Temperature Range | | $T_J$, $T_{STG}$ | -55 to +150 | °C |

## Electrical Characteristics (@$T_A$ = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Typ | Max | Unit | Test Condition |
|---|---|---|---|---|---|---|
| **OFF CHARACTERISTICS (Note 8)** | | | | | | |
| Drain-Source Breakdown Voltage | $BV_{DSS}$ | 12 | — | — | V | $V_{GS}$ = 0, $I_D$ = 250µA |
| Zero Gate Voltage Drain Current $T_J$ = +25°C | $I_{DSS}$ | — | — | 1 | µA | $V_{DS}$ = 9.6V, $V_{GS}$ = 0 |
| Gate-Source Leakage | $I_{GSS}$ | — | — | ±100 | nA | $V_{GS}$ = ±8V, $V_{DS}$ = 0 |
| **ON CHARACTERISTICS (Note 8)** | | | | | | |
| Gate Threshold Voltage | $V_{GS(TH)}$ | 0.3 | — | 1.0 | V | $V_{DS}$ = $V_{GS}$, $I_D$ = 250µA |
| Static Drain-Source On-Resistance | $R_{DS(ON)}$ | — | 6.6 | 8 | mΩ | $V_{GS}$ = 4.5V, $I_D$ = 5A |
| | | | 7.6 | 11 | | $V_{GS}$ = 3.0V, $I_D$ = 5A |
| | | | 8.5 | 11.6 | | $V_{GS}$ = 2.5V, $I_D$ = 5A |
| Diode Forward Voltage | $V_{SD}$ | — | 0.7 | 1.2 | V | $V_{GS}$ = 0, $I_S$ = 5A |
| **DYNAMIC CHARACTERISTICS (Note 9)** | | | | | | |
| Input Capacitance | $C_{iss}$ | — | 995 | — | pF | $V_{DS}$ = 6V, $V_{GS}$ = 0, f = 1.0MHz |
| Output Capacitance | $C_{oss}$ | — | 305 | — | | |
| Reverse Transfer Capacitance | $C_{rss}$ | — | 270 | — | | |
| Gate Resistance | $R_g$ | — | 1.5 | — | Ω | $V_{DS}$ = 0, $V_{GS}$ = 0, f = 1MHz |
| Total Gate Charge ($V_{GS}$ = 4.5V) | $Q_g$ | — | 13.6 | — | nC | $V_{DS}$ = 6V, $I_D$ = 5A |
| Total Gate Charge ($V_{GS}$ = 8V) | $Q_g$ | — | 23.4 | — | | |
| Gate-Source Charge | $Q_{gs}$ | — | 1.3 | — | | |
| Gate-Drain Charge | $Q_{gd}$ | — | 3.3 | — | | |
| Turn-On Delay Time | $t_{D(ON)}$ | — | 3.5 | — | ns | $V_{DS}$ = 6V, $V_{GS}$ = 4.5V, $R_G$ = 2Ω, $I_D$ = 5A |
| Turn-On Rise Time | $t_R$ | — | 6.6 | — | | |
| Turn-Off Delay Time | $t_{D(OFF)}$ | — | 17.5 | — | | |
| Turn-Off Fall Time | $t_F$ | — | 7.5 | — | | |
| Reverse-Recovery Time | $t_{RR}$ | — | 15 | — | ns | $I_F$ = 5A, di/dt = 200A/µs |
| Reverse-Recovery Charge | $Q_{RR}$ | — | 4 | — | nC | $I_F$ = 5A, di/dt = 200A/µs |

Notes:
5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
7. $I_{AS}$ and $E_{AS}$ ratings are based on low frequency and duty cycles to keep $T_J$ = +25°C.
8. Short duration pulse test used to minimize self-heating effect.
9. Guaranteed by design. Not subject to product testing.


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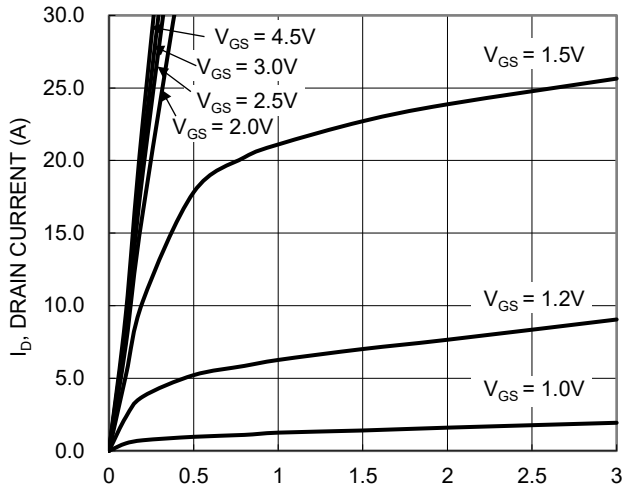



Figure 1. Typical Output Characteristic

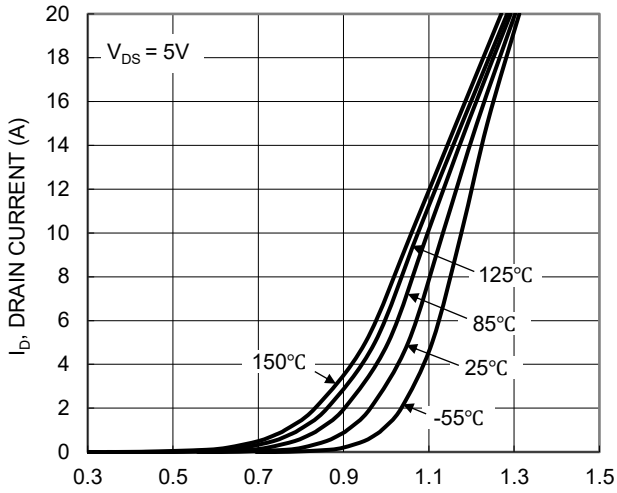



Figure 2. Typical Transfer Characteristic

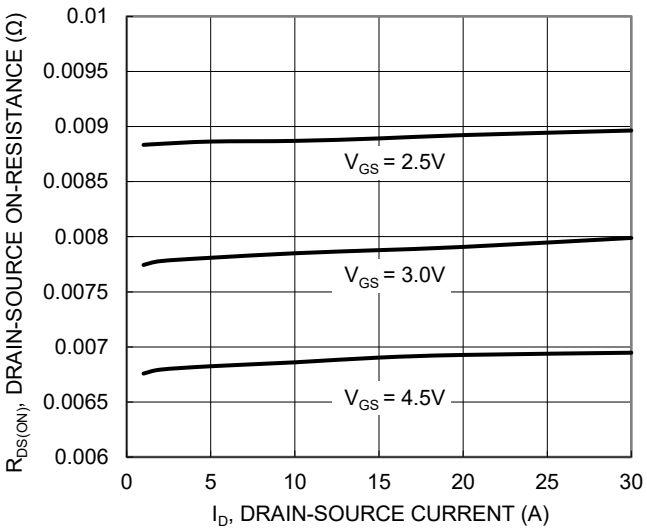



Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

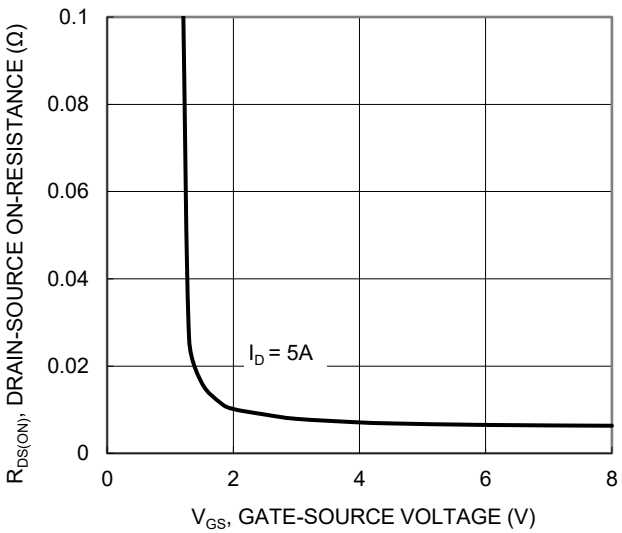



Figure 4. Typical Transfer Characteristic

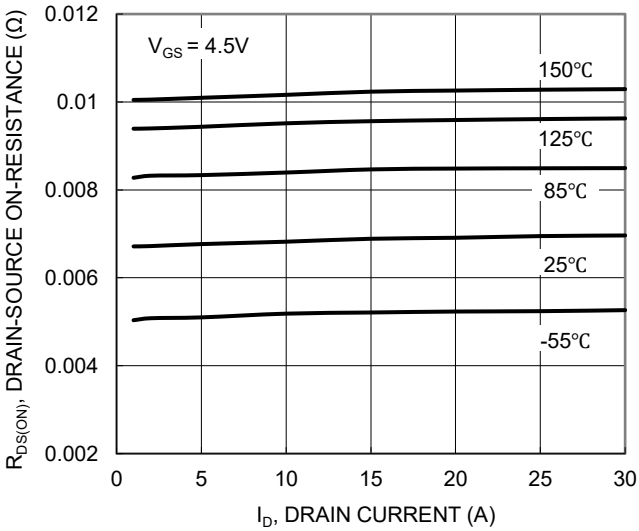



Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature

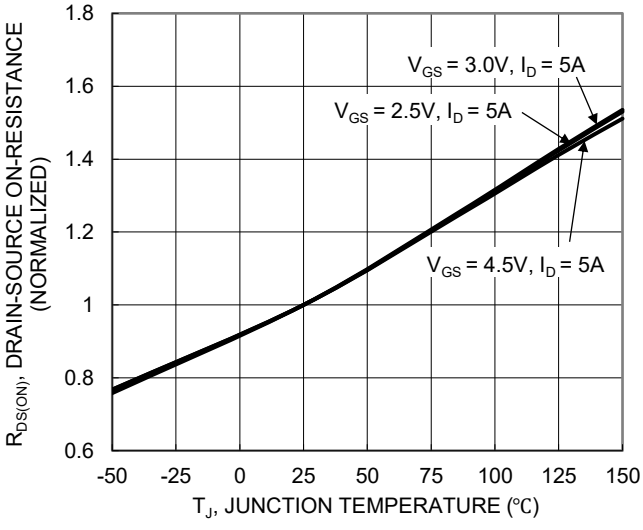



Figure 6. On-Resistance Variation with Junction Temperature


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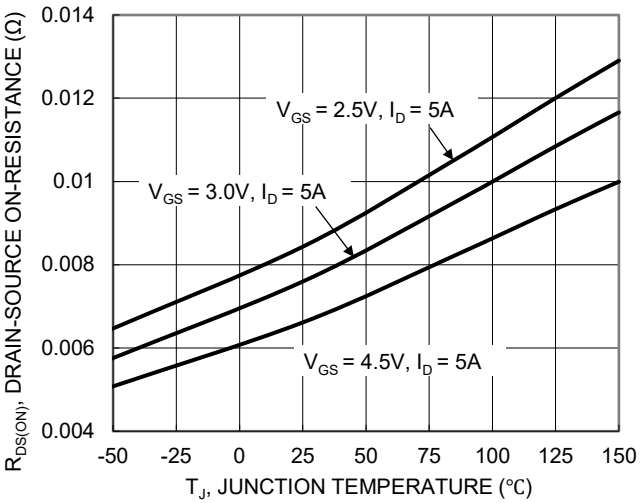



Figure 7. On-Resistance Variation with Junction Temperature

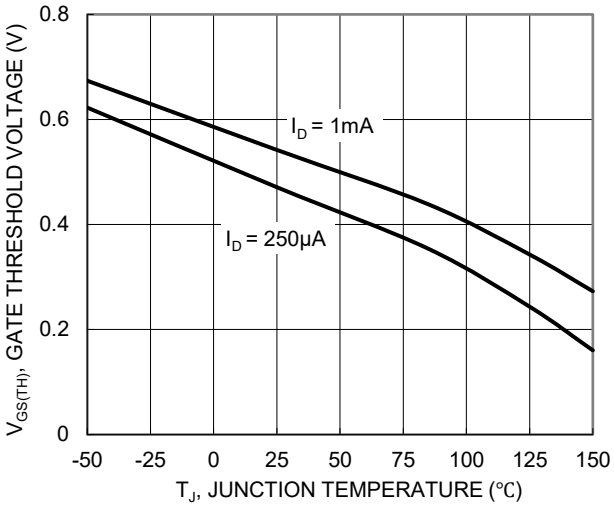



Figure 8. Gate Threshold Variation vs. Junction Temperature

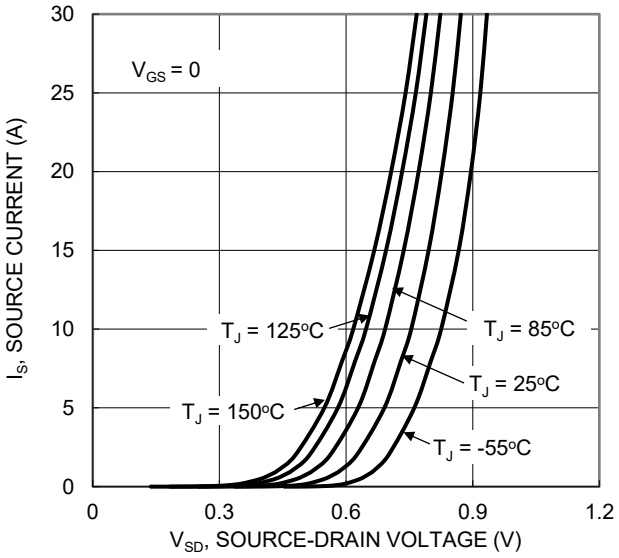



Figure 9. Diode Forward Voltage vs. Current

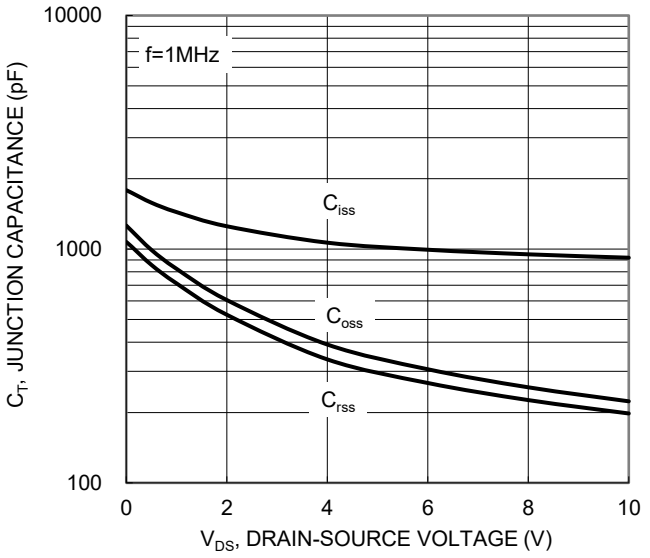



Figure 10. Typical Junction Capacitance

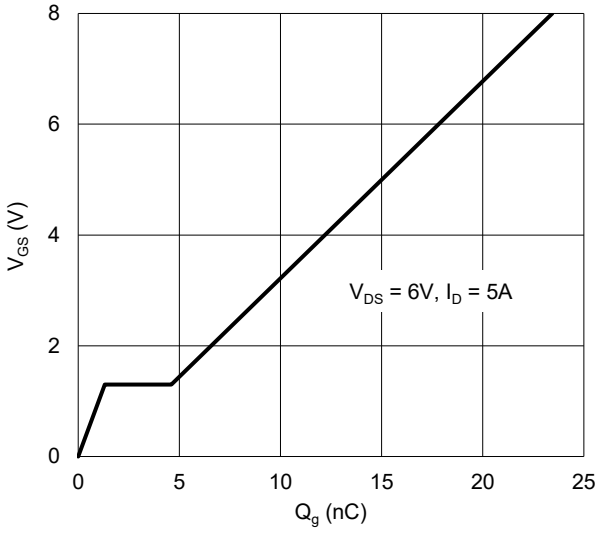



Figure 11. Gate Charge

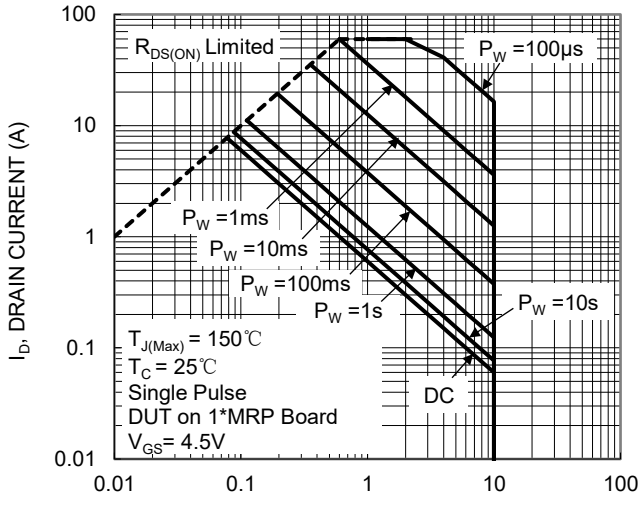



Figure 12. SOA, Safe Operation Area


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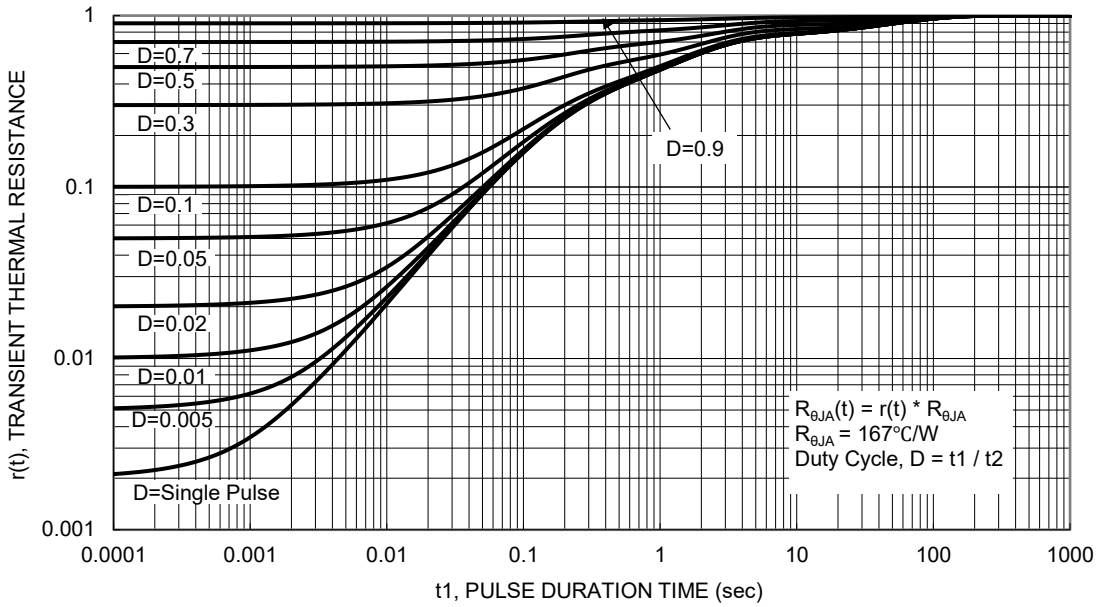


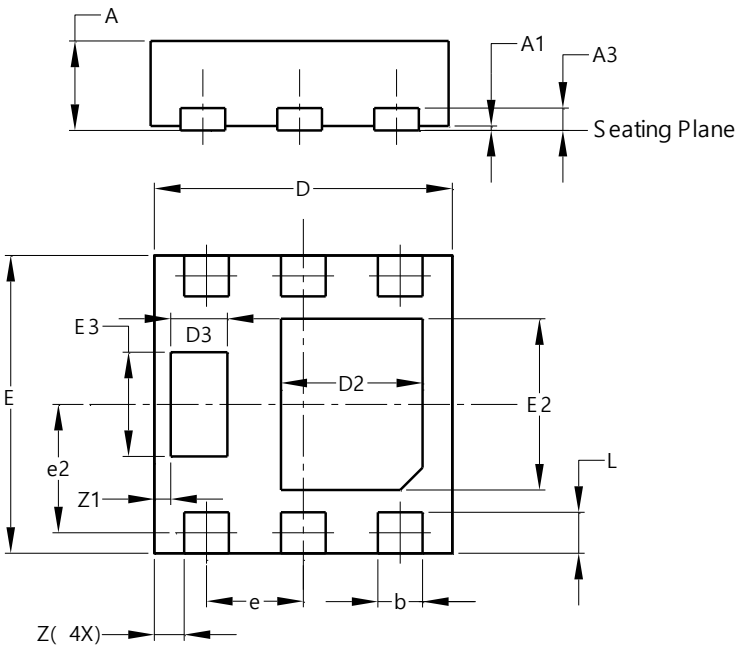

Figure 13. Transient Thermal Resistance


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## Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

**U-DFN2020-6 (Type F)**

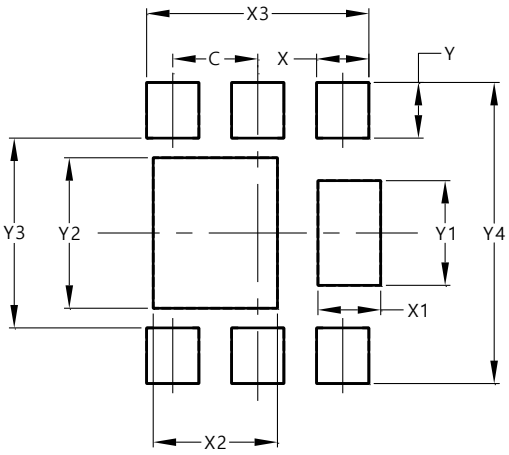



| U-DFN2020-6 (Type F) | | | |
|---|---|---|---|
| **Dim** | **Min** | **Max** | **Typ** |
| **A** | 0.57 | 0.63 | 0.60 |
| **A1** | 0.00 | 0.05 | 0.03 |
| **A3** | - | - | 0.15 |
| **b** | 0.25 | 0.35 | 0.30 |
| **D** | 1.95 | 2.05 | 2.00 |
| **D2** | 0.85 | 1.05 | 0.95 |
| **D2a** | 0.33 | 0.43 | 0.38 |
| **E** | 1.95 | 2.05 | 2.00 |
| **E2** | 1.05 | 1.25 | 1.15 |
| **E2a** | 0.65 | 0.75 | 0.70 |
| **e** | 0.65 BSC | | |
| **e2** | 0.863 BSC | | |
| **e3** | 0.70 BSC | | |
| **e4** | 0.325 BSC | | |
| **k** | 0.37 BSC | | |
| **k1** | 0.15 BSC | | |
| **k2** | 0.36 BSC | | |
| **L** | 0.225 | 0.325 | 0.275 |
| **z** | 0.20 BSC | | |
| **z1** | 0.110 BSC | | |
| **z2** | 0.20 BSC | | |
| **All Dimensions in mm** | | | |

## Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

**U-DFN2020-6 (Type F)**




| Dimensions | Value (in mm) |
|---|---|
| **C** | 0.650 |
| **X** | 0.400 |
| **X1** | 0.480 |
| **X2** | 0.950 |
| **X3** | 1.700 |
| **Y** | 0.425 |
| **Y1** | 0.800 |
| **Y2** | 1.150 |
| **Y3** | 1.450 |
| **Y4** | 2.300 |


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**Kategorilere göz atın**

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**Üreticileri görün**

### Toplu alım ve teklif

Listede olmayan ya da yüksek adetli parçalar için teklif isteyin.

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